

Technical Data Data Sheet N0101, Rev. -

Green products

Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 100A Peak
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

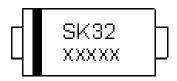
- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.21 grams (approx.)

├ ── _B	
	F H I G E

SWIC/DU-2 14AB						
Dim	Min	Min Max M		Max		
Α	5.59	6.22	0.220	0.245		
В	6.60	7.11	0.260	0.280		
С	2.75	3.25	0.108	0.128		
D	0.15	0.31	0.006	0.012		
E	7.75	8.13	0.305	0.320		
F	2.00	2.62	0.079	0.103		
G	0.05	0.20	0.002	0.008		
Н	0.76	1.27	0.030	0.050		
	In mm		In inch			

SMC/DO 214AB

Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Where XXXXX is YYWWL

SK32 = Part Name
 YY = Year
 WW = Week
 L = Lot Number

Ordering Information:

Device	Package	Shipping
SK32-G-SK310-G	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

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Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	SK32 -G	s кз з-G	SK34 -G	s K3 5-G	SK3 6-G	SK3 8-G	SK3 9-G	SK310-G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	20	30	40	50	60	80	90	100	٧
RMS Reverse Voltage	VR(RMS)	14	21	28	35	42	56	64	71	٧
Average Rectified Output Current @T _L = 75°C	lo	3.0					Α			
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	100				А				
Forward Voltage @I _F = 3.0A	VFM	0.55 0.75 0.85					٧			
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	İRM	0.5 20					mA			
Typical Thermal Resistance Junction to Ambient (Note 1)	RθJA	55				κw				
Operating Temperature Range	Tj	-65 to +125				°C				
Storage Temperature Range	Тѕтс	-65 to +150				°C				

Note: 1. Mounted on P.C. Board with 14mm2copper pad areas

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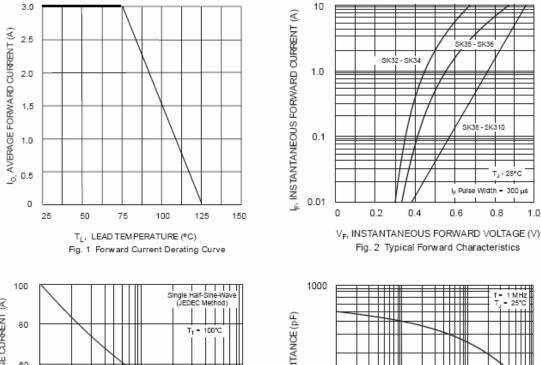
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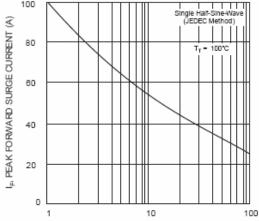
SK38 - SK310

T₁ - 25°C

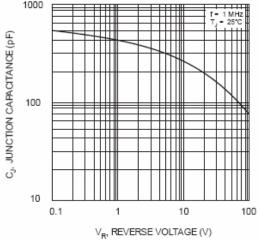
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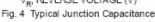
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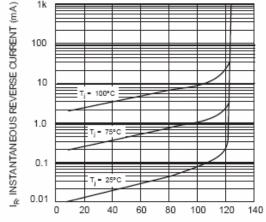












PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5. Typical Reverse Characteristics

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SK32-G-SK310-G 3.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

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